

MDL-III-1064L/1~200mW

INFRARED DIODE LASER AT 1064 nm





Infrared diode laser at 1064nm is made features of round spot, long lifetime, low cost and easy operating, which is widely used in measurement, spectrum analysis, etc.



SPECIFICATIONS

Wavelength (nm)	1064±5		
Output power (mW)	>1, 5, 10, ..., 200		
Spectral line width (nm)	<0.5		
Transverse mode	Near TEM ₀₀		
Operating mode	CW		
Power stability (rms, over 4 hours)	<1%, <3%, <5%		
Warm-up time (minutes)	<5		
Beam divergence, full angle (mrad)	<1.0		
Dimensions of beam at the aperture (mm)	~3.5		
Beam height from base plate (mm)	24.8		
Operating temperature (°C)	10~35		
Power supply (90-264VAC)	PSU-III-LED	PSU-III-FDA	PSU-III-OEM
Modulation option	TTL/Analog 1Hz-5KHz, 1Hz-10KHz, 1Hz-30KHz, and TTL on/off		
Expected lifetime (hours)	10000		
Warranty	1 year		



MxL-III-1064	PSU-III-LED	PSU-III-FDA	PSU-III-OEM
			
139(L)×73(W)×46.2(H) mm ³ , 0.6kg	153 (L) ×155(W) ×92 (H) mm ³ , 1.5kg	133 (L) ×130(W) ×65 (H) mm ³ , 1.2kg	100 (L) ×62(W) ×56 (H) mm ³ , 0.2kg
